# onsemi

# FFSP2065B

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

## Features

- Max Junction Temperature 175°C
- Avalanche Rated 94 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

## Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuit

## **ABSOLUTE MAXIMUM RATINGS**

(T<sub>C</sub> = 25°C, Unless otherwise specified)

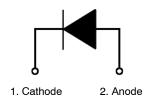
Symbol	Parame	Value	Unit		
V <sub>RRM</sub>	Peak Repetitive Revers	650	V		
E <sub>AS</sub>	Single Pulse Avalanche	94	mJ		
١ <sub>F</sub>	Continuous Rectified Fo T <sub>C</sub> < 141°C	20	A		
	Continuous Rectified Fo T <sub>C</sub> < 135°C	22.5			
I <sub>F, Max</sub>	Non-Repetitive Peak	T <sub>C</sub> = 25°C, 10 μs	882	А	
	Forward Surge Current	T <sub>C</sub> = 150°C, 10 μs	798		
I <sub>F, SM</sub>	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t <sub>p</sub> = 8.3 ms	84	A	
P <sub>tot</sub>	Power Dissipation $T_{C} = 25^{\circ}C$		150	W	
		T <sub>C</sub> = 150°C	25		
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage	–55 to +175	°C		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1.  $E_{AS}$  of 94 mJ is based on starting  $T_J = 25^{\circ}C$ , L = 0.5 mH,  $I_{AS} = 19.4$  A, V = 50 V.

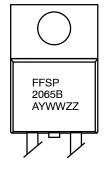
## DATA SHEET www.onsemi.com

## ELECTRICAL CONNECTION





## MARKING DIAGRAM



FFSP2065B	= Specific Device Code
Α	= Assembly Location
Y	= Year
WW	= Work Week
ZZ	= Assembly Lot Code

## ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

## FFSP2065B

### THERMAL CHARACTERISTICS

Symbol	Parameter	Ratings	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	1.0	°C/W

## **ELECTRICAL CHARACTERISTICS** $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>F</sub>	Forward Voltage	$I_F = 20 \text{ A}, \text{ T}_C = 25^{\circ}\text{C}$	-	1.38	1.7	V
		I <sub>F</sub> = 20 A, T <sub>C</sub> = 125°C	-	1.6	2.0	
		$I_F = 20 \text{ A}, T_C = 175^{\circ}\text{C}$	-	1.72	2.4	
I <sub>R</sub>	Reverse Current	$V_{R}$ = 650 V, $T_{C}$ = 25°C	-	0.5	40	μΑ
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 125^{\circ}\text{C}$	-	1	80	
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 175^{\circ}\text{C}$	-	2	160	
Q <sub>C</sub>	Total Capacitive Charge	V = 400 V	-	51	-	nC
С	Total Capacitance	V <sub>R</sub> = 1 V, f = 100 kHz	-	866	-	pF
		V <sub>R</sub> = 200 V, f = 100 kHz	-	80	-	
		V <sub>R</sub> = 400 V, f = 100 kHz	_	70	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFSP2065B	FFSP2065B	TO-220-2L	Tube	N/A	N/A	50 Units

## FFSP2065B

## **TYPICAL CHARACTERISTICS** $T_J = 25^{\circ}C$ UNLESS OTHERWISE NOTED

P<sub>TOT</sub>, POWER DISSIPATION (W)

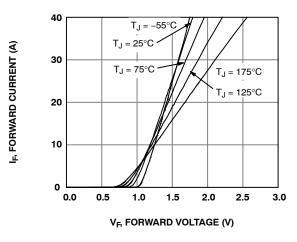


Figure 1. Forward Characteristics

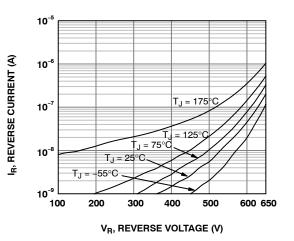
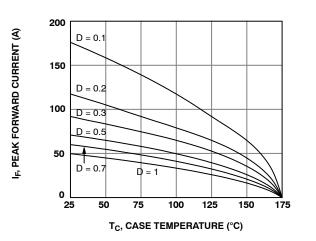
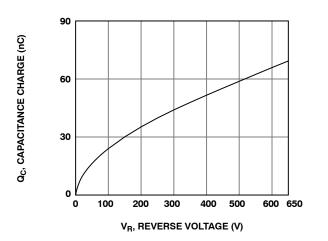
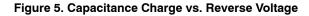


Figure 2. Reverse Characteristics



**Figure 3. Current Derating** 





180 120 60 0 25 50 75 100 125 150 175 T<sub>C</sub>, CASE TEMPERATURE (°C)

Figure 4. Power Dissipation

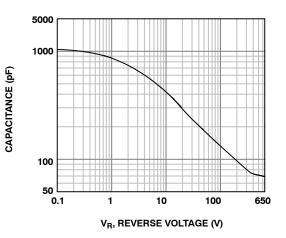
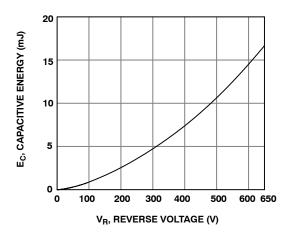
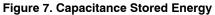


Figure 6. Capacitance vs. Reverse Voltage

## FFSP2065B

**TYPICAL CHARACTERISTICS**  $T_J = 25^{\circ}C$  UNLESS OTHERWISE NOTED (CONTINUED)





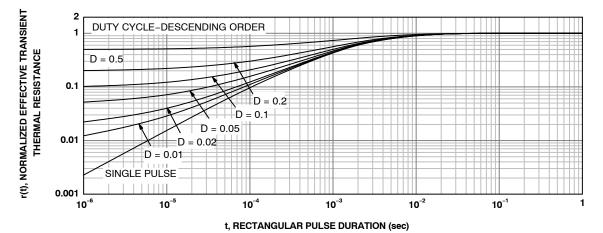
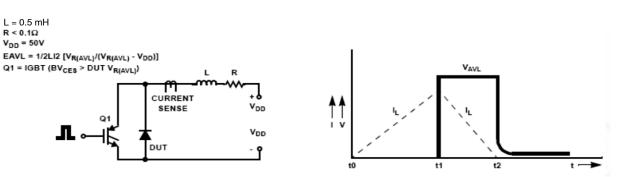


Figure 8. Junction-to-Case Transient Thermal Response Curve



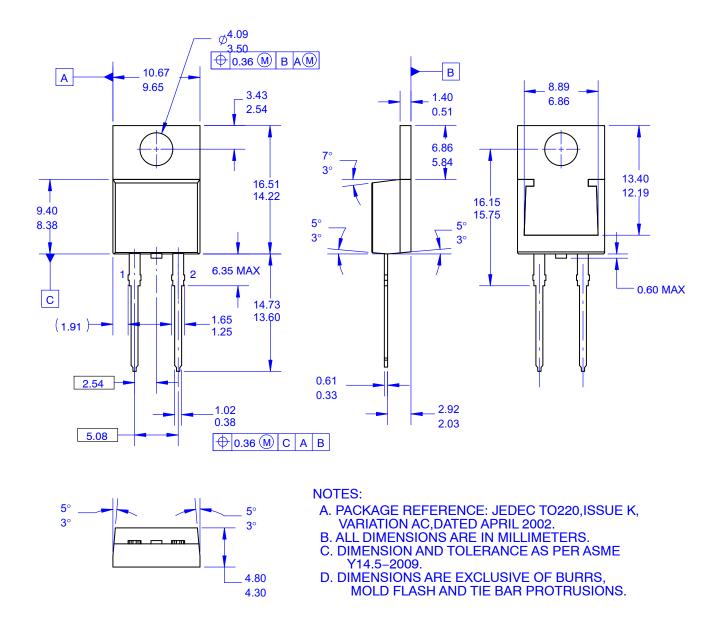
## **TEST CIRCUIT AND WAVEFORMS**

Figure 9. Unclamped Inductive Switching Test Circuit & Waveform



TO-220-2LD CASE 340BB ISSUE O

DATE 31 AUG 2016



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